

# Midium Power Transistors (80V / 700mA)

# 2SCR514P

## Structure

NPN Silicon epitaxial planar transistor

#### Features

 Low saturation voltage, typically V<sub>CE (sat)</sub> = 0.3V (Max.) (I<sub>C</sub> / I<sub>B</sub>= 300mA / 15mA)
High speed switching

#### Applications

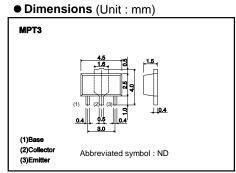
Driver

#### • Packaging specifications

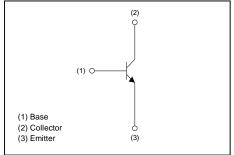
Туре	Package	Taping
	Code	T100
	Basic ordering unit (pieces)	1000
2SCR514P		0

## • Absolute maximum ratings (Ta = 25°C)

Parameter		Symbol	Limits	Unit
Collector-base voltage		V <sub>CBO</sub>	80	V
Collector-emitter voltage		V <sub>CEO</sub>	80	V
Emitter-base voltage		V <sub>EBO</sub>	6	V
Collector current	DC	Ι <sub>C</sub>	0.7	A
	Pulsed	I <sub>CP</sub> *1	1.4	A
Power dissipation		P <sub>D</sub> *2	0.5	W
		P <sub>D</sub> *3	2	W
Junction temperature		Tj	150	°C
Range of storage temperature		T <sub>stg</sub>	-55 to 150	°C



#### • Inner circuit (Unit : mm)



\*1 Pw=10ms, Single Pulse

\*2 Each terminal mounted on a recommended land.

\*3 Mounted on a ceramic board. (40x40x0.7mm<sup>3</sup>)

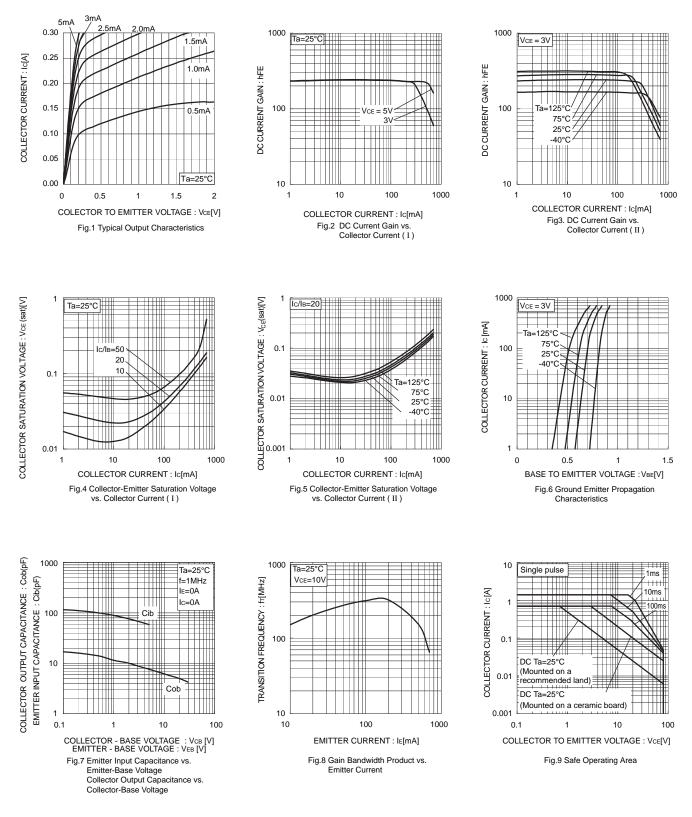
# •Electrical characteristic (Ta = 25°C)

Parameter		Min.	Тур.	Max.	Unit	Conditions	
Collector-emitter breakdown voltage	$BV_{CEO}$	80	-	-	V	l <sub>C</sub> = 1mA	
Collector-base breakdown voltage	$BV_{CBO}$	80	-	-	V	I <sub>C</sub> = 100μΑ	
Emitter-base breakdown voltage	$BV_{EBO}$	6	-	-	V	I <sub>E</sub> = 100μΑ	
Collector cut-off current	I <sub>CBO</sub>	-	-	1	μA	V <sub>CB</sub> = 80V	
Emitter cut-off current	I <sub>EBO</sub>	-	-	1	μA	V <sub>EB</sub> = 4V	
Collector-emitter staturation voltage	V <sub>CE(sat)</sub> *1	-	100	300	mV	I <sub>C</sub> = 300mA, I <sub>B</sub> = 15mA	
DC current gain	h <sub>FE</sub>	120	-	390	-	V <sub>CE</sub> = 3V, I <sub>C</sub> = 100mA	
Transition frequency	f <sub>T</sub> *1	-	320	-	MHz	V <sub>CE</sub> = 10V I <sub>E</sub> =-200mA, f=100MHz	
Collector output capacitance	C <sub>ob</sub>	-	6	-	pF	V <sub>CB</sub> = 10V, I <sub>E</sub> =0A f=1MHz	
Turn-on time	t <sub>on</sub> * <sub>2</sub>	-	50	-	ns	0.2541.25~4	
Storage time	t <sub>stg</sub> * <sub>2</sub>	-	650	-	ns	I <sub>C</sub> = 0.35A,I <sub>B1</sub> = 35mA, I <sub>B2</sub> =-35mA,V <sub>CC</sub> ~ 10V	
Fall time	t <sub>f</sub> *2	-	100	-	ns	1820011A, V <sub>CC</sub> ~10V	

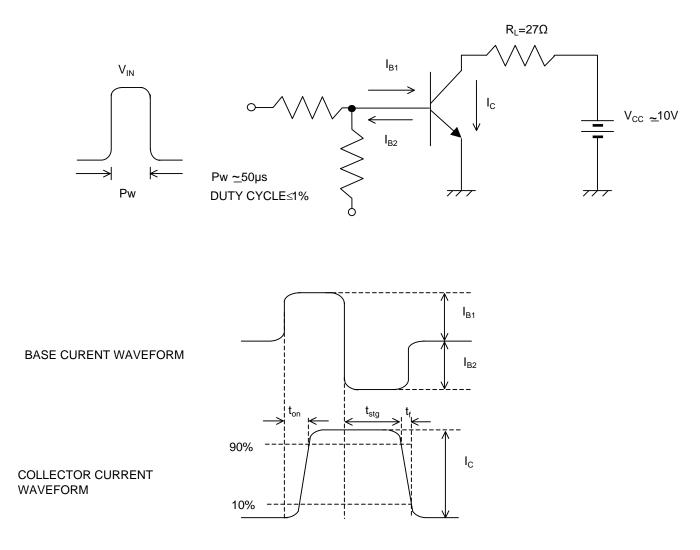
\*1 Pulsed

\*2 See switching time test circuit

### •Electrical characteristic curves



# •Switching time test circuit



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